

## SCHOTTKY-BARRIER DIODES

Silicon epitaxial Schottky Barrier diodes with an integrated p-n junction protection ring in a microminiature SOT-23 envelope intended for surface mounting.

The diodes feature an especially low forward voltage.

### QUICK REFERENCE DATA

Continuous reverse voltage	$V_R$	max. 30 V
Forward current (DC)	$I_F$	max. 200 mA
Forward voltage at $I_F = 10$ mA	$V_F$	max. 400 mV
Reverse recovery time when switched from $I_F = 10$ mA to $I_R = 10$ mA, $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA	$t_{rr}$	< 5 ns
Junction temperature	$T_j$	max. 125 °C

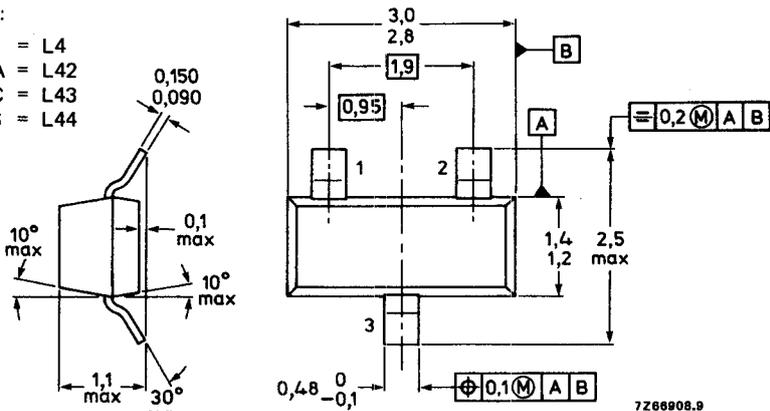
### MECHANICAL DATA

Dimensions in mm

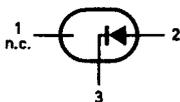
Fig.1 SOT-23.

Marking:

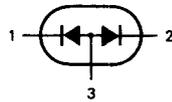
- BAT54 = L4
- BAT54A = L42
- BAT54C = L43
- BAT54S = L44



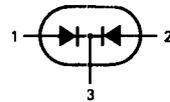
TOP VIEW



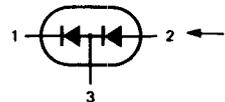
BAT54



BAT54A



BAT54C



BAT54S

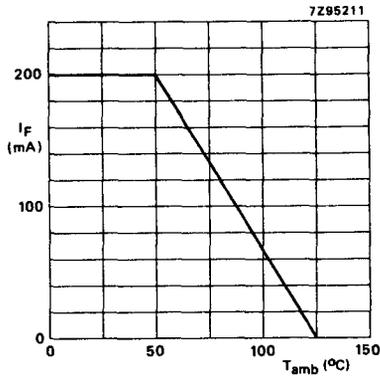


Fig. 2 Derating curve maximum ambient temperature.